Final Exam Toolbox Review

- 1. Quantum Mechanics
 - a) Fundamental Postulates & Schrödinger's Equation
 - b) Fundamental Systems by Hamiltonian
 - c) Periodic Potentials: Bloch Waveforms & Electronic Band Diagrams
 - 2. Solid State Physics
 - a) Density of States & Fermi-Dirac Distribution
 - b) Charge Carrier Density in Semi-Conductors (Intrinsic & Extrinsic)
 - c) *p-n* Junction Devices: Solar Cells & LEDs
 - 3. Electrodynamics, Optics, & Magnetism
 - a) Maxwell's Equations, Constitutive Relations, & The Damped Harmonic Oscillator
 - b) Optical Constants, Boundary Conditions, Snell's Law, & Light Interaction with Matter
 - c) Origins of Magnetism, Magnetic Hysteresis, & Magnetic Exchange Energy
 - 1. Quantum Mechanics
 - a) Fundamental Postulates & Schrödinger's Equation

I
$$(x,t)$$

$$\int_{-\infty}^{\infty} \psi_n^*(x)\psi_m(x)dx = \begin{cases} 1 & n = m \\ 0 & n \neq m \end{cases}$$

$$(x,t) \neq \infty$$

$$(x,t) \neq \infty$$

$$(x,t) = \psi^{\infty}$$

$$(x,t) = \psi^{1}(x) x \in (-\infty, a]$$

$$(x,t) = \psi^{1}(x) x \in (a, \infty)$$

$$\psi_{1}(a) = \psi_{1}(a)$$

$$\frac{\partial \psi_{1}}{\partial x}(a) = \frac{\partial \psi_{1}}{\partial x}(a)$$
II Probability Density $\rho(x) = \psi^{*}(x)\psi(x)dx$

$$1 = \int_{-\infty}^{\infty} \psi^{*}(x)\psi(x)dx$$

$$1 = \int_{-\infty}^{\infty} \psi^{*}(x)\psi(x)dx$$

$$1 = \int_{-\infty}^{\infty} \psi^{*}(x)\hat{A}\psi(x)dx$$

$$1 =$$

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b) Fundamental Systems by Hamiltonian		
System / Hamiltonian	Eigenenergies	Eigenfunctions
Free Electron $\widehat{H} = -\frac{\hbar^2}{2m} \frac{\partial^2}{\partial x^2}$ $V(x) = 0$	$E = \frac{\hbar^2 k^2}{2m} = \frac{p^2}{2m}$ $p = \hbar k = \sqrt{2mE}$	$u(x) = Ce^{\pm ikx}$
Particle-In-A-Box $\widehat{H} = -\frac{\hbar^2}{2m} \frac{\partial^2}{\partial x^2} + V(x)$ $V(x) = \begin{cases} 0 & 0 < x < L \\ \infty & x > L & \cup x < 0 \end{cases}$	$E_n = \frac{\hbar^2 \pi^2 n^2}{2mL^2} = \frac{\hbar^2 n^2}{8mL^2}$ n = 1,2,3,	$u_n(x) = \sqrt{\frac{2}{L}} \sin \frac{n\pi x}{L}$ $n = 1, 2, 3, \dots$
Simple Harmonic Oscillator $\hat{H} = -\frac{\hbar^2}{2m}\frac{\partial^2}{\partial x^2} + \frac{m\omega^2 x^2}{2}$	$\omega = \sqrt{\frac{\kappa}{m}}$	$u_n(x) = \sqrt{\frac{1}{2^n n!}} \left(\frac{m\omega}{\pi\hbar}\right)^{\frac{1}{4}} e^{-\frac{1m\omega}{2-\hbar}x^2} H_n\left(x\sqrt{\frac{m\omega}{\hbar}}\right)$ $H_n\left(x\sqrt{\frac{m\omega}{\hbar}}\right) \text{ are the Hermite polynomials.}$
Hydrogen Atom $\widehat{H} = -\frac{\hbar^2}{2\mu} \nabla_r^2 - \frac{e^2}{4\pi\epsilon_0 r}$	n = 0,1,2, $E_n = -\frac{E_I}{n^2} \cong -\frac{13.6 \text{ eV}}{n^2}$ n = 1,2,3,	$u_n(x) = R_{n,l}(r)Y_l^m(\theta, \phi)$ $l \le n$; $0 \le l \le n - 1$; $-l + 1 \le m \le l - 1$
Periodic Potential $\widehat{H} = -\frac{\hbar^2}{2m} \frac{\partial^2}{\partial x^2} + \sum_G V_G e^{iGx}$	$E_n(k)$ Energy Band Diagram	$u_{n,k}(x) = e^{ikx} \sum_{G} C_{k-G} e^{-iGx}$ $-\frac{g}{2} \le k \le \frac{g}{2}; g = \frac{2\pi}{a}$

b) Fundamental Systems by Hamiltonian

c) Periodic Potentials: Bloch Waveforms & Electronic Band Diagrams

 $\frac{\text{Periodic Trends}}{N = \text{Atomic Number}}$ $N \uparrow \rightarrow V \downarrow, a \uparrow, K \downarrow, m \uparrow$

Periodic Potentials

$$V(x) = \sum_{G} V_{G} e^{iGx}$$
Central Equation

$$\left(\frac{\hbar^{2}}{2m}k^{2} - E\right)C_{k} + \sum_{G} V_{G}C_{k-G} = 0$$

$$u_{n,k}(x) = e^{ikx}\sum_{G} C_{k-G}e^{-iGx}$$

Near the band-edge:

$$E_c = E_g + \frac{\hbar^2}{2m_c^*}k^2$$
$$E_v = -\frac{\hbar^2}{2m_c^*}k^2$$

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- 2. Solid State Physics
 - a) Density of States & Fermi-Dirac Distribution

Finding an ηD system density of states:

First calculate the total number of states N

 $\eta D k$ – space volume of entire Brillouin Zone

$$N = \#$$
 of Fermions per State (Based off of spin) $\frac{1}{\eta D k} - \text{space volume between atoms}$

$$N = 2\frac{Ck^{\eta}}{\left(\frac{2\pi}{L}\right)^{\eta}} = \frac{2\dot{C}k^{\eta}L^{r}}{(2\pi)^{\eta}}$$

Next use free electron energy to express N as a function of E

$$k = \frac{\sqrt{2mE}}{\hbar} \to N = \frac{2C(2mE)^{\frac{1}{2}}L^{\eta}}{(2\pi\hbar)^{\eta}}$$

Divide *N* by the η D real space volume to get the volume state density *n*

$$n = \frac{N}{V} = \frac{N}{L^{\eta}} = \frac{2C(2mE)^{\frac{1}{2}}}{(2\pi\hbar)^{\eta}}$$

Finally, find g(E) by taking the derivative of n with respect to E

$$g(E) = \frac{dn}{dE} = \frac{\eta C (2m)^{\frac{\eta}{2}}}{(2\pi\hbar)^{\eta}} E^{\frac{\eta}{2}-1}$$

The Fermi-Dirac distribution gives the probability at a temperature *T* and energy *E* that a fermion will occupy that state. Electrons are fermions, so we apply this distribution when calculating total charge carrier densities.

$$f(E,T) = \frac{1}{e^{\frac{E-E_F}{k_B T}} + 1}$$

b) Charge Carrier Density in Semi-Conductors (Intrinsic & Extrinsic)

General formula to calculate the electron charge carrier density in material with lowest conduction energy E_0 .

$$n(T) = \int_{E_0}^{\infty} f(E,T)g(E)dE$$

For semiconductors, using the degenerate semiconductor approximation, the carrier densities can be calculated as follows:

$$n_{c}(T) = \int_{E_{c}}^{\infty} f(E,T)g_{c}(E)dE$$

$$p_{v}(T) = \int_{-\infty}^{E_{v}} (1 - f(E,T))g_{v}(E)dE$$

$$n_{c}(T) \cong N_{c}(T)e^{\frac{-(E_{c}-\mu)}{k_{B}T}} N_{c}(T) \cong \frac{1}{4}\left(\frac{2m_{c}^{*}k_{B}T}{\pi\hbar^{2}}\right)^{\frac{3}{2}}$$

$$p_{v}(T) \cong P_{v}(T)e^{\frac{(E_{v}-\mu)}{k_{B}T}} P_{v}(T) \cong \frac{1}{4}\left(\frac{2m_{v}^{*}k_{B}T}{\pi\hbar^{2}}\right)^{\frac{3}{2}}$$
Law of Mass Action
$$n_{c}(T)p_{v}(T) = N_{c}(T)P_{v}(T)e^{\frac{-E_{g}}{k_{B}T}}$$
Intrinsic SC
$$n_{c} = p_{v} = n_{i}$$

$$n_{c}p_{v} = n_{i}^{2} = N_{c}(T)P_{v}(T)e^{\frac{-E_{g}}{k_{B}T}}$$

$$\mu = F = E_{v} + \frac{E_{g}}{2} + \frac{3}{4}k_{B}T\ln\left(\frac{m_{v}^{*}}{m_{c}^{*}}\right)$$

Extrinsic SC p-type material (dopant is electron acceptor)

$$p_{v} \approx N_{A}$$

$$n_{c} \approx \frac{n_{i}^{2}}{N_{A}}$$

$$F = +\frac{E_{g}}{2} + \frac{3}{4} k_{B} T \ln\left(\frac{m_{v}^{*}}{m_{c}^{*}}\right) - k_{B} T \ln\left(\frac{N_{A}}{n_{i}}\right)$$

n-type material (dopant is electron donor)

$$p_{\nu} \approx \frac{n_i^2}{N_D}$$

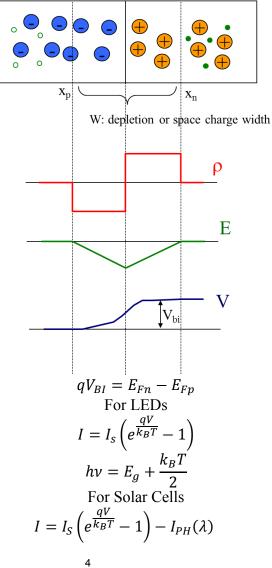
$$n_c \approx N_D$$

$$F = +\frac{E_g}{2} + \frac{3}{4} k_B T \ln\left(\frac{m_{\nu}^*}{m_c^*}\right) + k_B T \ln\left(\frac{N_D}{n_i}\right)$$

Conductivity

$$\sigma = n_c e \mu_e + p_v e \mu_h$$

c) *p-n* Junction Devices: Solar Cells & LEDs



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- 3. Electrodynamics, Optics, & Magnetism
 - a) Maxwell's Equations, Constitutive Relations, & The Damped Harmonic Oscillator Maxwell's Equations

$$\vec{\nabla} \cdot \vec{D} = \rho$$

$$\vec{\nabla} \cdot \vec{B} = 0$$

$$\vec{\nabla} \times \vec{E} + \frac{\partial \vec{B}}{\partial t} = 0$$

$$\vec{\nabla} \times \vec{H} - \frac{\partial \vec{D}}{\partial t} = \vec{J}$$
Constitutive Relations
$$\vec{D} = \varepsilon \vec{E} = \varepsilon_0 \vec{E} + \vec{P}$$

$$\vec{B} = \mu \vec{H} = \mu_0 \vec{H} + \vec{M}$$
Damped Harmonic Oscillator
$$\vec{P} = \frac{\omega_0^2 \varepsilon_0 \chi_0}{\omega_0^2 - \omega^2 - i\sigma\omega} \vec{E} = \varepsilon_0 \chi(\omega) \vec{E}$$

$$\chi = \chi' + i\chi''$$

$$\varepsilon = \varepsilon_0 (1 + \chi)$$

b) Optical Constants, Boundary Conditions, Snell's Law, & Light Interaction with Matter Optical Constants & Relations

$$\frac{1}{c^2} = \mu \varepsilon$$

$$c = \frac{c_0}{n}$$

$$\mu = \mu_r \mu_0$$

$$\varepsilon = \varepsilon_r \varepsilon_0$$

$$\omega = c |\vec{k}| = \frac{c_0 2\pi}{n \lambda}$$

$$n' \equiv n + i\alpha$$

$$\vec{E} \times \vec{H} = \vec{S}$$
Boundary Conditions
$$B_1 = B_2$$

$$\sigma = D_2 - D_1$$

$$\vec{E}_{1||} = \vec{E}_{2||}$$

$$\vec{K} = \vec{H}_{2||} - \vec{H}_{1||}$$
Reflection & Snell's Law
$$\theta_i = \theta_r$$

$$n_1 \sin \theta_i = n_2 \sin \theta_t$$
Wave Guides
$$\sin \theta_c = \frac{n_2}{n_1}$$

$$n \sin \theta_{MAX} = \sqrt{n_1^2 - n_2^2}$$
Anti-Reflective Coatings & Quarter Wave Stacks
$$n_I = \sqrt{n_0 n_s}$$

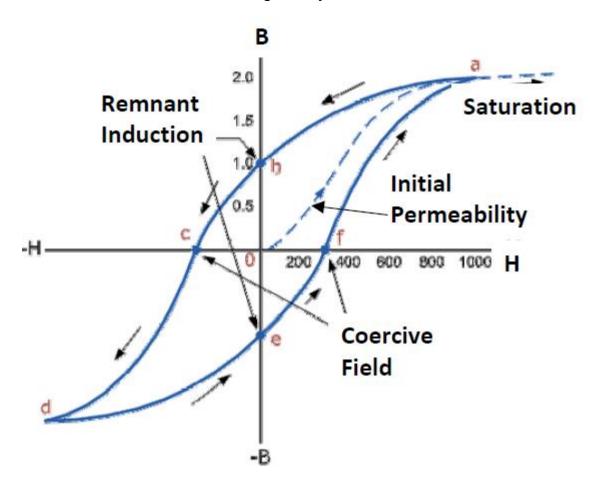
$$d = \frac{\lambda_0}{4n_I}$$
Photonic Dispersion Relationship
$$\cos K(\beta, \omega) a = \frac{1}{2}(M_{11} + M_{22})$$

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c) Origins of Magnetism, Magnetic Hysteresis, & Magnetic Exchange Energy Origins of Magnetism

$$\vec{B} = \mu_0 \vec{H} + \vec{M}$$
$$\vec{M} = \mu_0 \chi_M \vec{H}$$
$$\vec{M} = N\vec{\mu} \neq N q_{mag} \vec{x}$$
$$\mu_B = \gamma \hbar$$
$$\gamma = \frac{q}{2m}$$
Total Angular Momentum
$$\vec{J} = \vec{S} + \vec{L}$$
$$\hat{J}^2 \Psi = \hbar^2 j (j+1) \Psi$$
$$\mu = \mu_B \sqrt{j(j+1)}$$

Magnetic Hysteresis

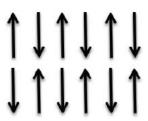


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Hard Magnets = High Coercivity Soft Magnets = Low Coercivity 3.024 Electrical, Optical, and Magnetic Properties of Materials Recitation 15

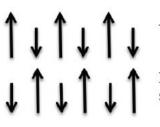
$$\widehat{H}_{magnetic} = -\sum_{i,j} J_{ij} \hat{S}_i \cdot \hat{S}_j + \frac{\mu_B}{\hbar} \sum_i \vec{B} \cdot \hat{S}_i = \sum_i \left(-\sum_j J_{ij} \hat{S}_j + \frac{\mu_B}{\hbar} \vec{B} \right) \cdot \hat{S}_i = \sum_i \left(\frac{\mu_B}{\hbar} (\vec{B}_{ex} + \vec{B}) \right) \cdot \hat{S}_i$$

$$\bigwedge \bigwedge \bigwedge \bigwedge \bigwedge \bigwedge \bigwedge \underset{J_{ex} > 0 \Rightarrow \text{ exchange energy is minimized when } \hat{S}_i \uparrow \uparrow \hat{S}_j$$
Large spontaneous magnetization at $T < T_c$



Anti-ferromagnetic:

- $J_{ex} < 0 \Rightarrow$ exchange energy is minimized when $\hat{S}_i \uparrow \downarrow \hat{S}_j$
- No net magnetization, but ordering at $T < T_N$



Ferrimagnetic:

 $J_{ex} < 0 \Rightarrow$ exchange energy is minimized when $\hat{S}_i \uparrow \downarrow \hat{S}_j$

Reduced net magnetization (as compared to ferromagnetic materials), spontaneous ordering at $T < T_N$

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